III. Fast / Ultra Fast / Super Fast Recovery Rectifier

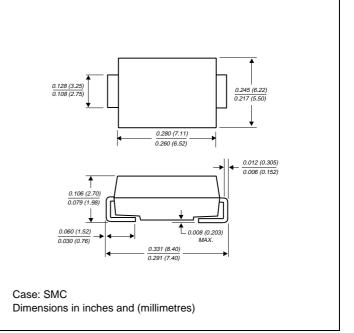
5.0A Surface Mount Super Fast Recovery Rectifier ES5A~ES5J (Package: SMC (DO-214AB))

FEATURES

- For surface mounted applications.
- Glass passivated junction chip.
- Built-in strain relief, ideal for automated placement.
- Plastic material used carries Underwriters Laboratory Flammability Classification 94V-0.
- Super Fast recovery for high efficiency.
- High temperature soldering : 250 /10 seconds at terminals.

MECHANICAL DATA

- Case : Molded plastic
- Terminals : Solder plated
- · Polarity : Indicated by cathode band
- Weight : 0.220 grams



Ratings & Electrical Characteristics

Ratings at 25 ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20%.

| Characteristics | Symbol | ES5A | ES5B | ES5C | ES5D | ES5E | ES5G | ES5J | Units |
|---|------------------|----------------|------|------|------|------|------|-------|-------|
| Maximum recurrent peak reverse voltage | V _{RRM} | 50 | 100 | 150 | 200 | 300 | 400 | 600 | Volts |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 105 | 140 | 210 | 280 | 420 | Volts |
| Maximum DC blocking voltage | V _{DC} | 50 | 100 | 150 | 200 | 300 | 400 | 600 | Volts |
| Maximum average forward rectified current at $T_L=75$ | lo | 5.0 | | | | | | | Amps |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load. (JEDEC Method) | I _{FSM} | 150 | | | | | | | Amps |
| Maximum instantaneous forward voltage @ 5.0 A | VF | 0.95 1.30 1.70 | | | | | 1.70 | Volts | |
| Maximum DC reverse current@Ta =25at rated DC blocking voltage@Ta =100 | I _R | 10 300 | | | | | | | μA |
| Maximum reverse recovery time (Note 1) | Trr | 35 | | | | | | | ns |
| Typical junction capacitance (Note 2) | Cj | 58 | | | | | | | PF |
| Typical thermal resistance | Rth-JA | 47 | | | | | | | /W |
| Operating temperature range | Tj | -65 to +150 | | | | | | | |
| Storage temperature range | Tstg | -65 to +150 | | | | | | | |

Notes:

1. Reverse recovery test conditions: I_F=0.5A, I_R=1.0A, I_{RR}=0.25A

2. Measured at 1.0 MHz and applied V_R =4.0V.

Ratings and Characteristic Curves of ES5A~ES5J

